

# VS-4ESH02HM3/86A Datasheet

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DiGi Electronics Part Number	VS-4ESH02HM3/86A-DG
Manufacturer	<a href="#">Vishay General Semiconductor - Diodes Division</a>
Manufacturer Product Number	VS-4ESH02HM3/86A
Description	DIODE GEN PURP 200V 4A TO277A
Detailed Description	Diode 200 V 4A Surface Mount TO-277A (SMPC)

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## Purchase and inquiry

**Manufacturer Product Number:**

VS-4ESH02HM3/86A

**Series:**

FRED Pt®

**Technology:**

Standard

**Current - Average Rectified (Io):**

4A

**Speed:**

Fast Recovery =&lt; 500ns, &gt; 200mA (Io)

**Current - Reverse Leakage @ Vr:**

2 µA @ 200 V

**Grade:**

Automotive

**Mounting Type:**

Surface Mount

**Supplier Device Package:**

TO-277A (SMPC)

**Base Product Number:**

4ESH02

**Manufacturer:**

Vishay General Semiconductor - Diodes Division

**Product Status:**

Active

**Voltage - DC Reverse (Vr) (Max):**

200 V

**Voltage - Forward (Vf) (Max) @ If:**

930 mV @ 4 A

**Reverse Recovery Time (trr):**

20 ns

**Capacitance @ Vr, F:**

-

**Qualification:**

AEC-Q101

**Package / Case:**

TO-277, 3-PowerDFN

**Operating Temperature - Junction:**

-65°C ~ 175°C

## Environmental & Export classification

**RoHS Status:**

ROHS3 Compliant

**REACH Status:**

REACH Unaffected

**HTSUS:**

8541.10.0080

**Moisture Sensitivity Level (MSL):**

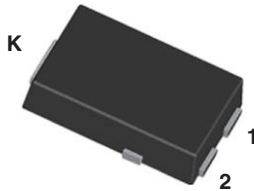
1 (Unlimited)

**ECCN:**

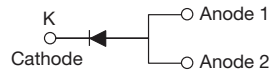
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## Hyperfast Rectifier, 4 A FRED Pt<sup>®</sup>

### eSMP<sup>®</sup> Series



SMPC (TO-277A)



### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	4 A
$V_R$	200 V
$V_F$ at $I_F$	0.73 V
$t_{rr}$ (typ.)	27 ns
$T_J$ max.	175 °C
Package	SMPC (TO-277A)
Circuit configuration	Single

### FEATURES

- Hyperfast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, piezo-injection, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

### MECHANICAL DATA

**Case:** SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating  
Halogen-free, RoHS compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		200	V
Average rectified forward current	$I_{F(AV)}$	$T_{Sp} = 165$ °C	4	A
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25$ °C	130	
Operating junction and storage temperatures	$T_J, T_{Stg}$		-55 to +175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25$ °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100$ $\mu$ A	200	-	-	V
Forward voltage	$V_F$	$I_F = 4$ A	-	0.86	0.93	
		$I_F = 4$ A, $T_J = 125$ °C	-	0.73	0.79	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	2	$\mu$ A
		$T_J = 125$ °C, $V_R = V_R$ rated	-	2	10	
Junction capacitance	$C_T$	$V_R = 200$ V	-	23	-	pF



DYNAMIC RECOVERY CHARACTERISTICS ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	$t_{rr}$	$I_F = 1.0\text{ A}$ , $di_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	27	-	ns	
		$I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{rr} = 0.25\text{ A}$	-	-	25		
		$T_J = 25\text{ }^\circ\text{C}$	-	20	-		
		$T_J = 125\text{ }^\circ\text{C}$	-	31	-		
Peak recovery current	$I_{RRM}$	$I_F = 4\text{ A}$ $di_F/dt = 200\text{ A}/\mu\text{s}$ $V_R = 160\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	2.2	-	A
			$T_J = 125\text{ }^\circ\text{C}$	-	4.4	-	
Reverse recovery charge	$Q_{rr}$		$T_J = 25\text{ }^\circ\text{C}$	-	22	-	nC
			$T_J = 125\text{ }^\circ\text{C}$	-	70	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	$^\circ\text{C}$
Thermal resistance, junction to mount	$R_{thJM}$		-	2.2	3	$^\circ\text{C}/\text{W}$
Thermal resistance, junction to ambient	$R_{thJA}$		-	85	-	
Approximate weight			0.1			g
			0.0035			oz.
Marking device		Case style SMPC (TO-277A)	JEH2			

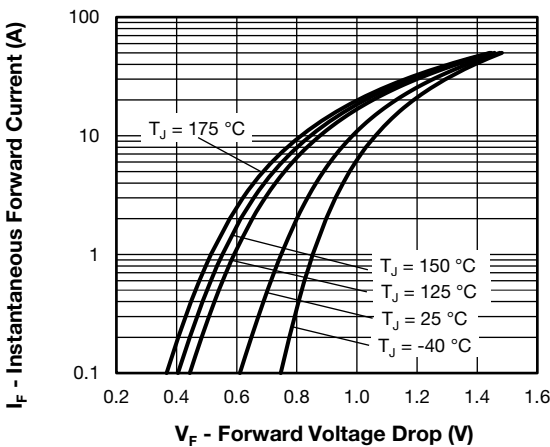


Fig. 1 - Typical Forward Voltage Drop Characteristics

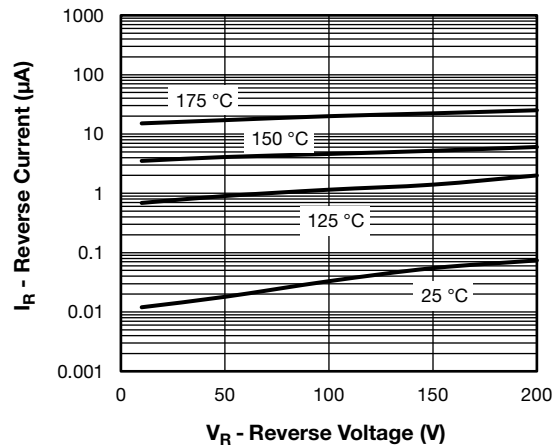


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

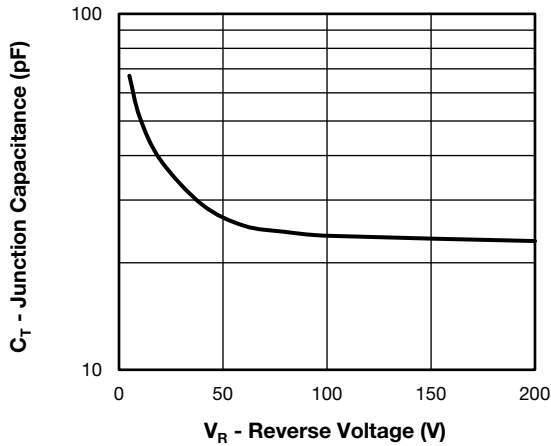


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

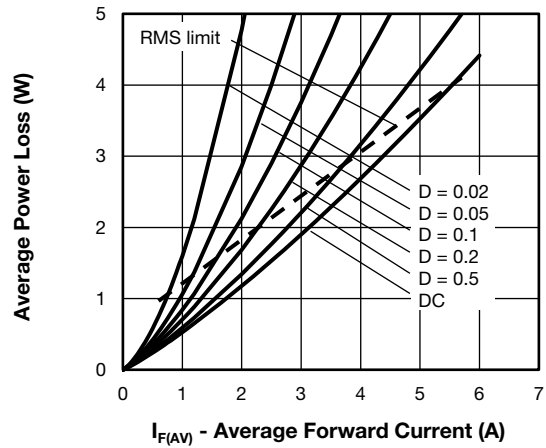


Fig. 5 - Forward Power Loss Characteristics

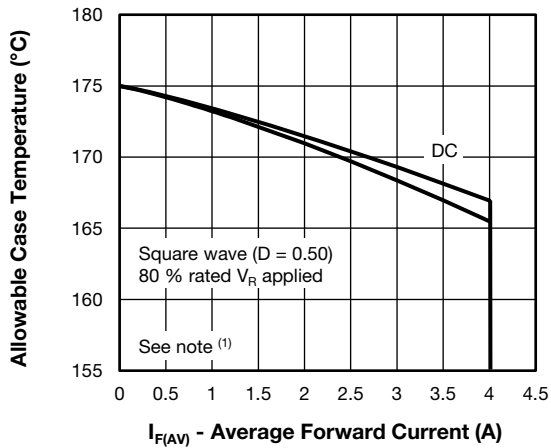


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

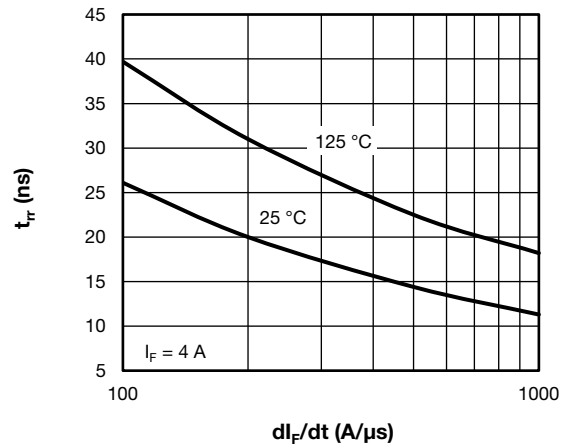


Fig. 6 - Typical Reverse Recovery Time vs.  $dI_F/dt$

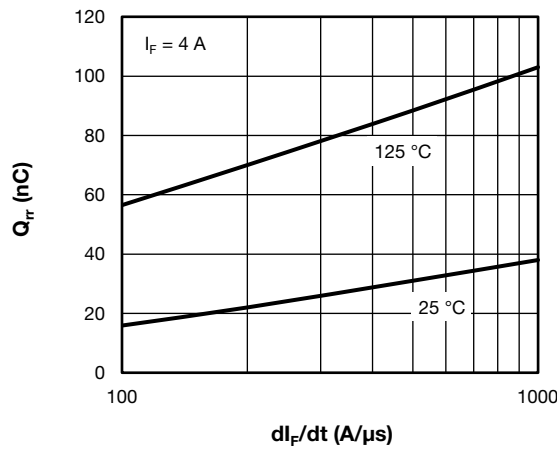


Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

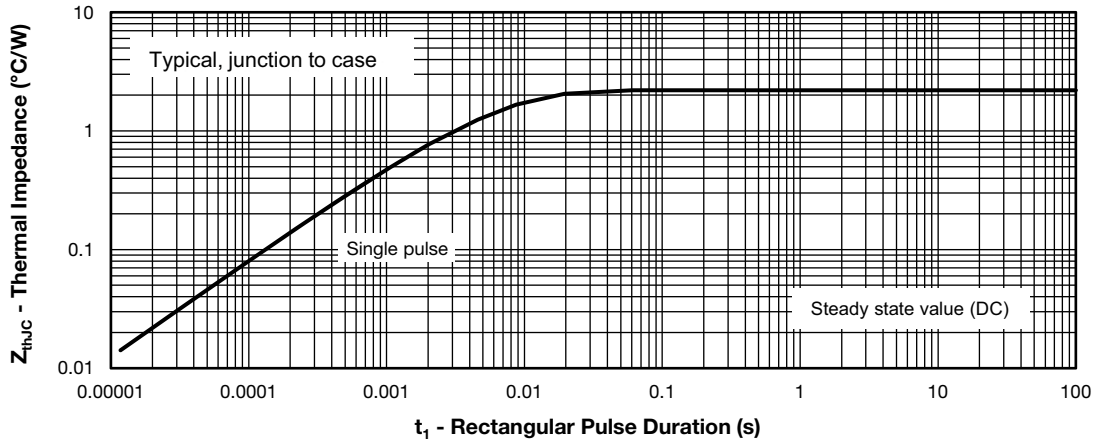


Fig. 8 - Transient Thermal Impedance, Junction to Case

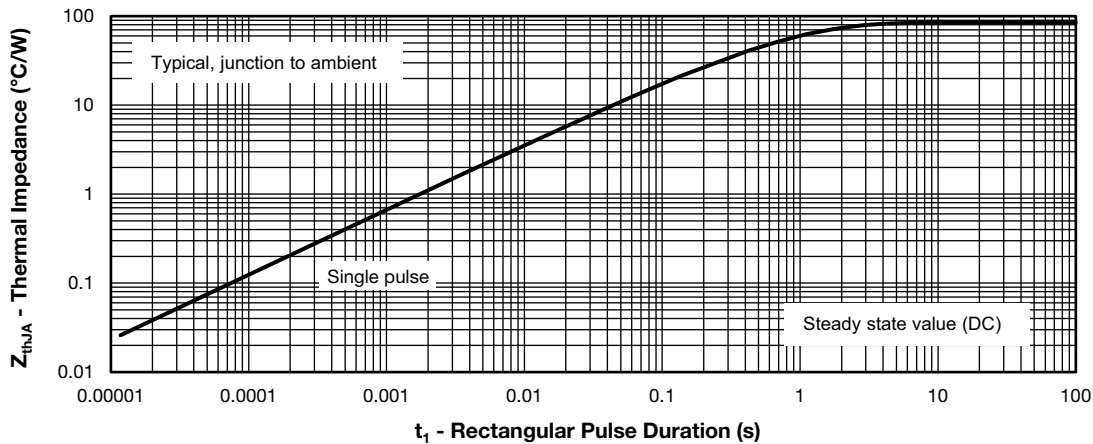
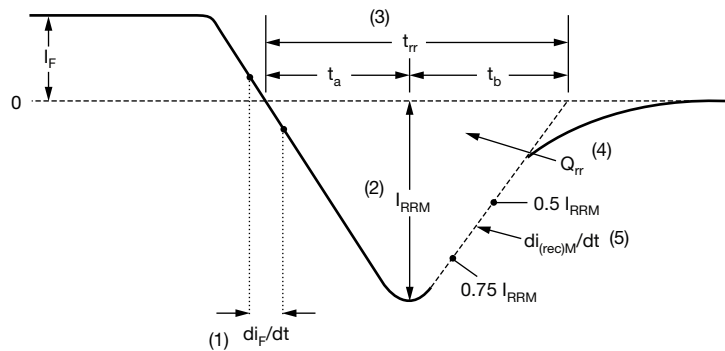


Fig. 9 - Transient Thermal Impedance, Junction to Ambient



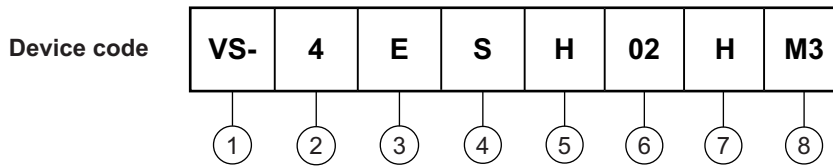
- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.
- (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$
- (5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (4 = 4 A)
- 3** - Circuit configuration:  
E = single diode
- 4** - S = SMPC package
- 5** - Process type,  
H = hyperfast recovery
- 6** - Voltage code (02 = 200 V)
- 7** - H = AEC-Q101 qualified
- 8** - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

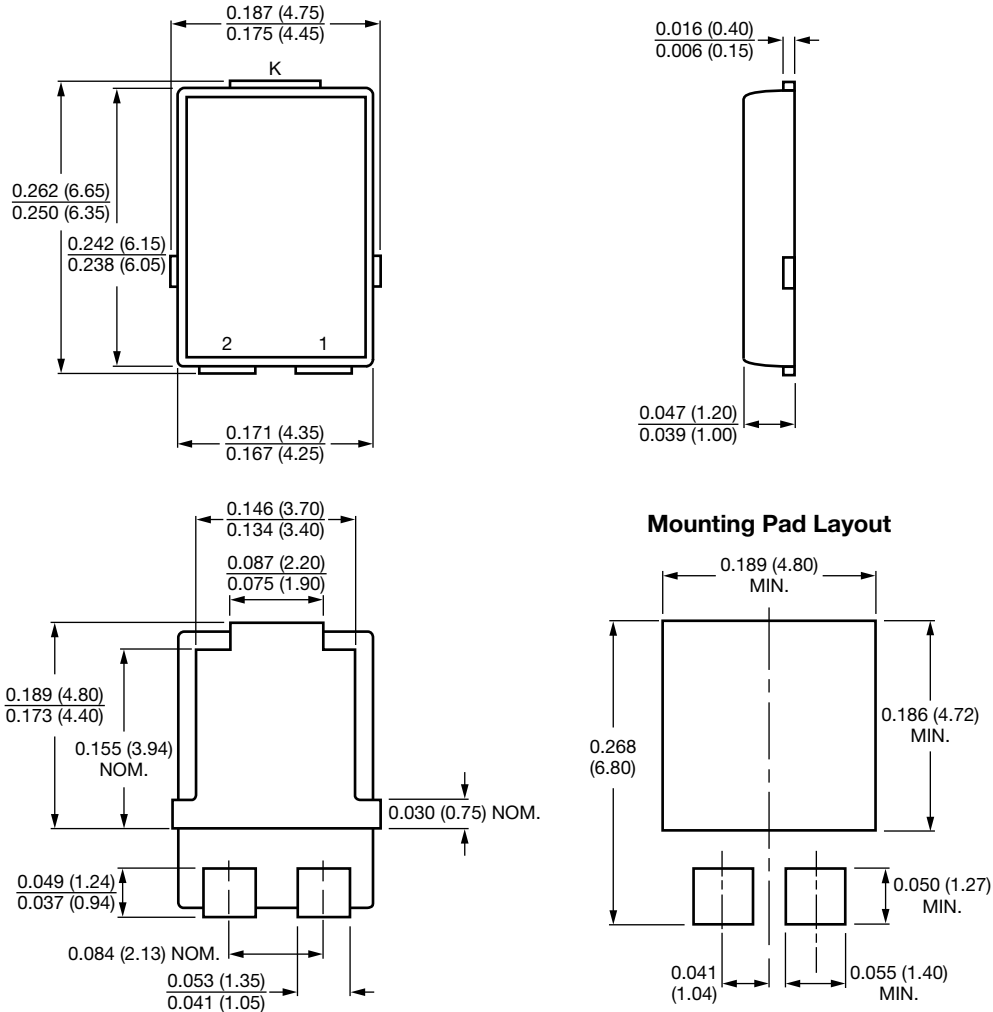
ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-4ESH02HM3/86A	1500	1500	7" diameter plastic tape and reel
VS-4ESH02HM3/87A	6500	6500	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95570">www.vishay.com/doc?95570</a>
Part marking information	<a href="http://www.vishay.com/doc?95565">www.vishay.com/doc?95565</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>
SPICE model	<a href="http://www.vishay.com/doc?96073">www.vishay.com/doc?96073</a>



## SMPC (TO-277A)

**DIMENSIONS** in inches (millimeters)



Conform to JEDEC® TO-277A



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